

# HSS104

## Silicon Epitaxial Planar Diode for High Speed Switching

# HITACHI

Rev. 1  
Aug. 1995

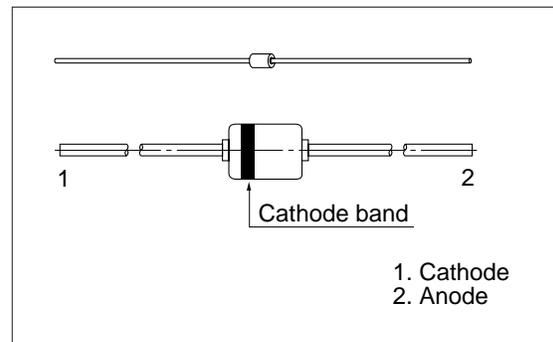
### Features

- Short reverse recovery time and forward recovery time.
- Suitable for 5mm pitch high speed automatic insertion.
- Small glass package (MHD) enables easy mounting and high reliability.

### Ordering Information

Type No.	Cathode band	Package Code
HSS104	Blue	MHD

### Outline



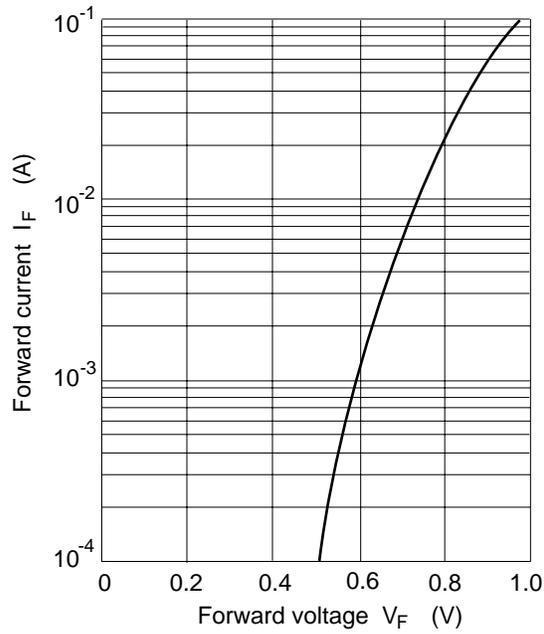
### Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Value	Unit
Peak reverse voltage	$V_{RM}$	40	V
Reverse voltage	$V_R$	35	V
Peak forward current	$I_{FM}$	300	mA
Non-Repetitive peak forward surge current	$I_{FSM}^*$	0.4	A
Average forward current	$I_o$	110	mA
Power dissipation	$P_d$	300	mW
Junction temperature	$T_j$	175	°C
Storage temperature	$T_{stg}$	-65 to +175	°C

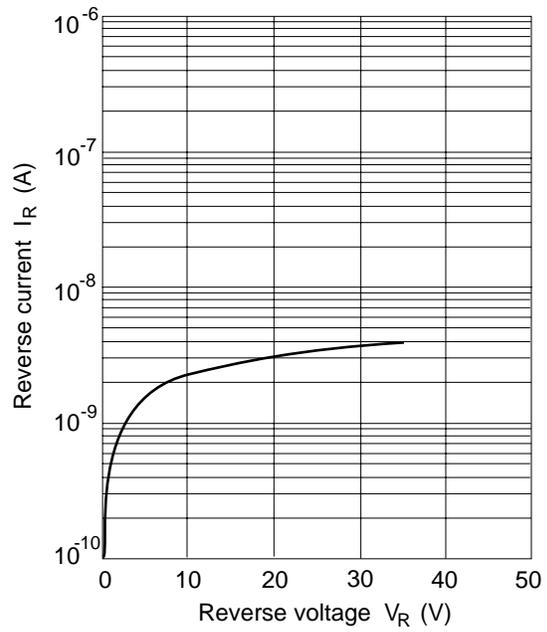
\* Within 1s forward surge current.

### Electrical Characteristics (Ta = 25°C)

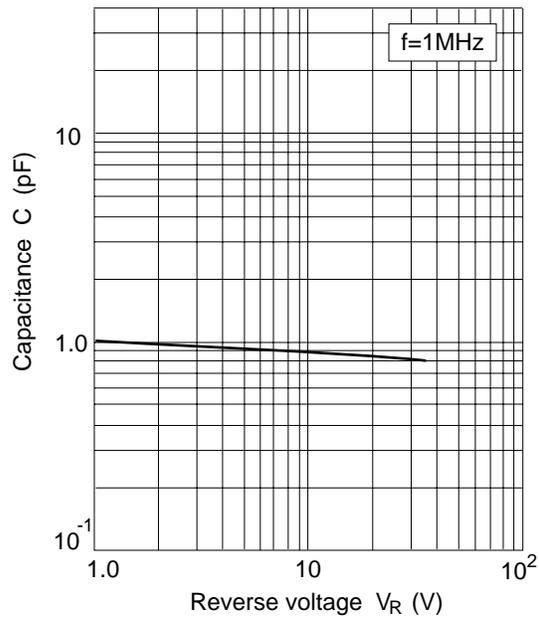
Item	Symbol	Min	Typ	Max	Unit	Test Condition
Forward voltage	$V_F$	—	—	1.2	V	$I_F = 100 \text{ mA}$
Reverse current	$I_R$	—	—	0.5	$\mu\text{A}$	$V_R = 35 \text{ V}$
Capacitance	C	—	—	3.0	pF	$V_R = 0.5 \text{ V}, f = 1 \text{ MHz}$
Reverse recovery time	$t_{rr}$	—	—	3.0	ns	$I_F = 10 \text{ mA}, V_R = 6 \text{ V}, R_L = 50 \Omega$



**Fig.1 Forward current Vs. Forward voltage**



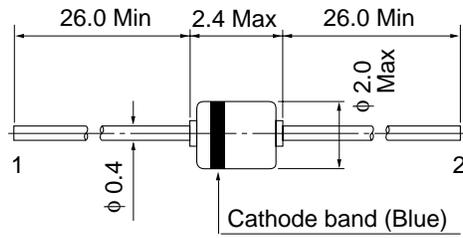
**Fig.2 Reverse current Vs. Reverse voltage**



**Fig.3 Capacitance Vs. Reverse voltage**

Package Dimensions

Unit: mm



- 1 Cathode
- 2 Anode

HITACHI Code	MHD
JEDEC Code	DO-34
EIAJ Code	—
Weight (g)	0.084